NSN 5961-00-774-4449

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Inclosure Material:

Metal

Overall Length:

0.215 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Emitter

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 35.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

3.30 amperes source cutoff current

Power Rating Per Characteristic:

70.0 watts small-signal input power, common-collector

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 pin

Specification Data:

80131-release5340 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0